FLAT GAIN, HIGH IP3

Monolithic Amplifier

CMA-62+

50Ω 0.01 to 6 GHz

THE BIG DEAL

- Ceramic, Hermetic, Nitrogen Filled
- Flat Gain, ±0.7 dB Over 50 to 4000 MHz
- Gain, 15.4 dB Typ. at 2 GHz
- High P1dB, +19 dBm Typ. at 2 GHz
- High IP3, +39.0 dBm Typ. at 50 MHz; +33.0 dBm at 2 GHz
- Excellent ESD Protection, Class 1C for HBM
- Small Size, 3x3x1.14 mm
- No External Matching Components Required

Generic photo used for illustration purposes only

CASE STYLE: DL1721

+RoHS Compliant
The +Suffix identifies RoHS Compliance.
See our website for methodologies and qualifications

MIL SCREENING AVAILABLE
PLEASE CONSULT APPLICATIONS DEPT.

APPLICATIONS

- Base Station Infrastructure
- Portable Wireless
- CATV & DBS
- MMDS & Wireless LAN
- LTE

PRODUCT OVERVIEW

CMA-62+ (RoHS compliant) is a wideband amplifier fabricated using HBT technology and offers ultra flat gain over a broad frequency range and with high IP3. In addition, the CMA-62+, has good input and output return loss over a broad frequency range without the need for external matching components and has demonstrated excellent reliability. The MMIC amplifier is bonded to a multilayer integrated LTCC substrate, and then hermetically sealed under a controlled nitrogen atmosphere with gold-plated covers and eutectic AuSn solder. These amplifiers are capable of meeting MIL requirements for gross leak, fine leak, thermal shock, vibration, acceleration, mechanical shock, and HTOL. The testing can be done if requested.

KEY FEATURES

Feature	Advantages
Broad Band: 0.01 to 6.0 GHz	Broadband covering primary wireless communications bands: Cellular, PCS, LTE, WiMAX, SATELLITE IF
Ultra Flat Gain	±0.6 dB over 50 to 3000 MHz; ±0.10 dB over 700 to 2700 MHz eliminates need for gain flattening for most applications.
High IP3 vs. DC Power Consumption +39 dBm Typical at 0.05 GHz +37 dBm Typical at 0.8 GHz	The CMA-62+ matches industry leading IP3 performance relative to device size and power consumption. The combination of the design and HBT Structure provides enhanced linearity over a broad frequency range as evidence in the IP3 being typically 20 dB above the P1dB point to 0.8 GHz. This feature makes this amplifier ideal for use in: • Driver amplifiers for complex waveform up converter paths • Drivers in linearized transmit systems
No External Matching Components Required	CMA-62+ provides Input and Output Return Loss of 10-23 dB up to 7 GHz without the need for any external matching components.
Ceramic Hermetic Package	Low Inductance, repeatable performance, excellent reliability.

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ELECTRICAL SPECIFICATIONS[1,2] AT +25°C, UNLESS NOTED OTHERWISE

Parameter	Condition (GHz)	Min.	Typ.	Max.	Units
Frequency Range[2]		0.01		6	GHz
Gain	0.05	15.5	16.6	18.0	dB
	0.8	14.5	15.6	16.5	
	2.0		15.4		
	3.0		15.4		
	4.0	14.0	15.2	16.0	
	6.0		13.7		
Gain Flatness	0.05-3.0		±0.6		dB
	0.7-2.6		±0.1		
Input Return Loss	0.05	10.0	16.5		dB
	0.8		13.6		
	2.0		14.7		
	3.0		22.7		
	4.0		25.9		
	6.0		13.9		
Output Return Loss	0.05	12.0	14.1		dB
	0.8		14.3		
	2.0		14.0		
	3.0		10.9		
	4.0		10.0		
	6.0		14.0		
Reverse Isolation	2.0		21.9		dB
Output Power @ 1 dB Compression	0.05	+17.5	+19.9		dBm
	0.8	+17.5	+19.6		
	2.0	+17.2	+19.2		
	3.0		+17.6		
	4.0		+15.4		
	6.0		+11.8		
Noise Figure	0.05		4.8	6.2	dB
	1.0		5.2		
	2.0		5.4	6.6	
	3.0		5.3		
	4.0		5.6		
	6.0		5.7		
Output IP3	0.05	31.5	39.0		dB
	0.8		36.5		
	2.0		33.4		
	3.0		29.6		
	4.0		27.3		
	6.0		23.2		
Device Operating Voltage		+4.8	+5.0	+5.2	V
Device Operating Current		72	82	92	mA
DC Current Variation vs. Temperature[3]			62		µA/°C
DC Current Variation vs. Voltage			0.035		mA/mV
Thermal Resistance, Junction-to-Ground Lead			64		°C/W

1. Measured on Mini-Circuits Characterization test board TB-656-62+. See Characterization Test Circuit (Fig. 1).
2. Low Frequency cut-off determined by external coupling capacitors and external bias choke.
3. (Current at +85°C - Current at -45°C)/130

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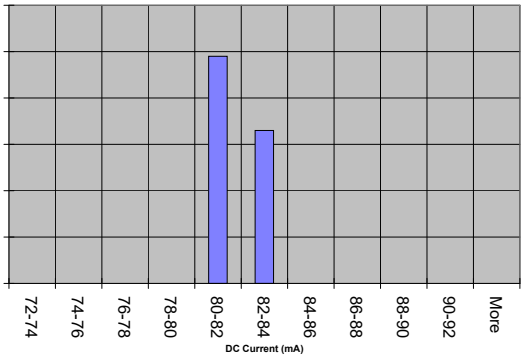
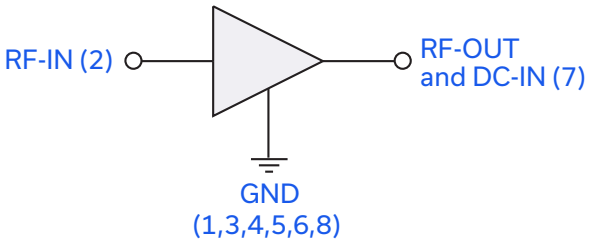
ABSOLUTE MAXIMUM RATINGS

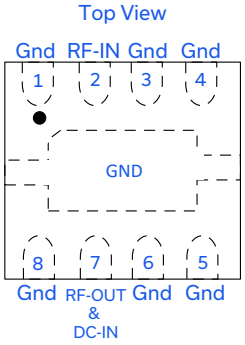
Parameter	Ratings
Operating Temperature (Ground Lead)	-55°C to +105°C
Storage Temperature	-65°C to +125°C
Operating Current at +5 V	120 mA
Power Dissipation	0.725 W
Input Power (CW)	+24 dBm
DC Voltage on Pin 3	+6 V

Permanent damage may occur if any of these limits are exceeded. These ratings are not intended for continuous normal operation.
For continuous operation, do not exceed +5.2 V device voltage.



SIMPLIFIED SCHEMATIC AND PAD DESCRIPTION





Function	Pin Number	Description
RF-IN	2	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
RF-OUT and DC-IN	7	RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit", Fig. 2.
GND	1,3,4,5,6,8, Bottom Center Paddle	Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance.

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CHARACTERIZATION TEST CIRCUIT

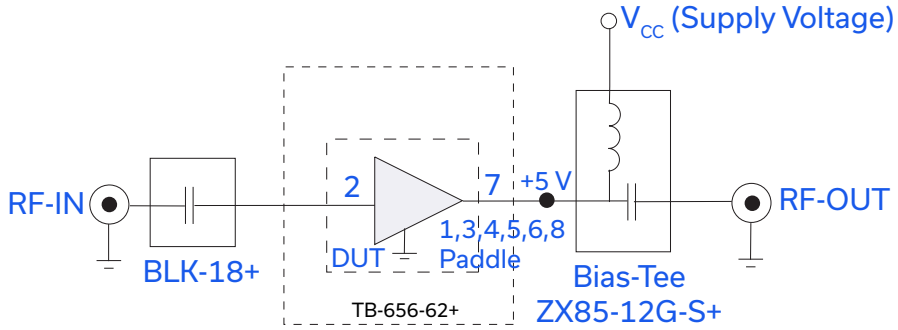


Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization test board TB-656-62+) Gain, Return Loss, Output Power at 1 dB Compression (P1dB), Output IP3 (OIP3) and Noise Figure measured using Agilent's N5242A PNA-X microwave network analyzer.

Conditions:
1. Gain and Return Loss: P_{IN}= -25 dBm
2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/tone at output.

RECOMMENDED APPLICATION CIRCUIT

(Refer to evaluation board for PCB Layout and component values)

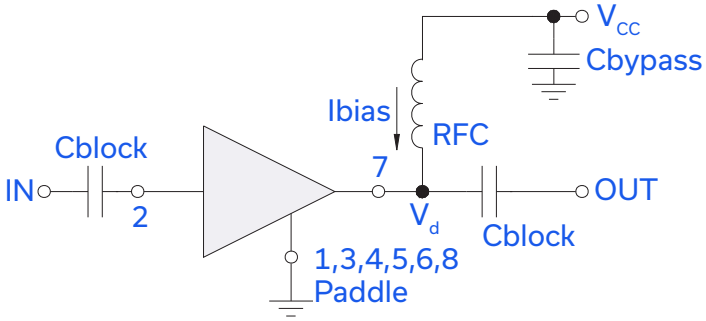
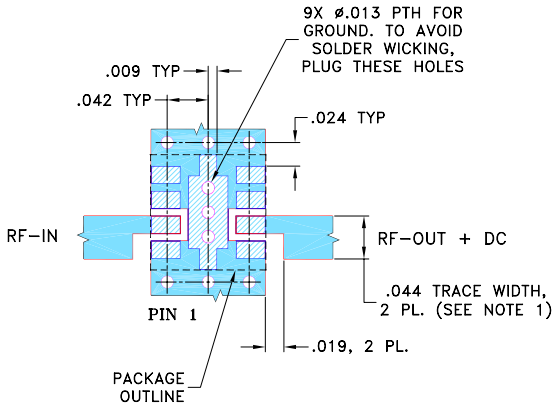


Fig 2. Test Board includes case, connectors, and components soldered to PCB for component values, please see evaluation board drawing.

SUGGESTED PCB LAYOUT (PL-366)

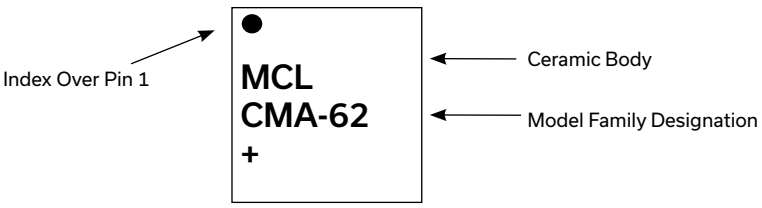


NOTES:
1. TRACE WIDTH IS SHOWN FOR ROGERS RO4350B WITH DIELECTRIC THICKNESS .020" ± .0015"; COPPER: 1/2 OZ. EACH SIDE. FOR OTHER MATERIALS TRACE WIDTH AND GAP MAY NEED TO BE MODIFIED.
2. BOTTOM SIDE OF THE PCB IS CONTINUOUS GROUND PLANE.

DENOTES PCB COPPER LAYOUT WITH SMOBC (SOLDER MASK OVER BARE COPPER)

DENOTES COPPER LAND PATTERN FREE OF SOLDER MASK

PRODUCT MARKING



Markings in addition to model number designation may appear for internal quality control purposes.

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ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASHBOARD. CLICK HERE

Performance Data & Graphs	Data Table Swept Graphs S-Parameter (S2P Files) Data Set (.zip file)
Case Style	DL1721 Ceramic package, exposed paddle, Terminal Finish: Ni,Pd,Au
Tape & Reel **Standard Quantities Available on Reel**	F66-1 7" Reels with 20, 50, 100, 200, 500, 1000 & 2000 devices
Suggested Layout for PCB Design	PL-366
Evaluation Board	TB-656-62+
Environmental Ratings	ENV68

ESD RATING

Human Body Model (HBM): Class 1C (1000 V to < 2000 V) in accordance with ANSI/ESD STM 5.1 - 2001
Machine Model (MM): Class M2 (100 V to < 200 V) in accordance with ANSI/ESD STM5.2-1999

MSL RATING

Moisture Sensitivity: MSL1 (these parts are hermetic, air cavity and therefore, MSL ratings do not strictly apply. For handling purpose, use MSL1)

QUALIFICATION TESTING

The table below shows the initial qualification testing performed. If required, parts can be subjected to 100% screening and qualifications testing per MIL standard requirement.

	Test Description	Test Method/Process	Results
1	Hermeticity (fine and gross leak)	MIL-STD-202 Method 112, Cond. C & D	Pass
2	Acceleration, 30Kg, Y1 Direction	MIL-STD-883 Method 2001 Cond. E	Pass
3	Vibration , 10-2000Hz sine, 20g, 3 axis	MIL-STD-202 Method 204, Cond. D	Pass
4	Mechanical shock	MIL-STD-202 Method 213, Cond . A	Pass
5	PIND 20G's @130 Hz	MIL-STD-750 Method 2052.2	Pass
6	Temp Cycle -55C/+125C, 1000 Cycles	MIL-STD-202 Method 107	Pass
7	Autoclave, 121C, RH 100%, 15 Psig, 96 hrs	JESD22-A102C	Pass
8	HTOL, 1000hrs, 105C at rated Voltage condition	MIL-STD-202 Method 108, Cond . D	Pass
9	Bend Test	JESD22-B113	Pass
10	Resistance to soldering heat, 3x reflow, 260C peak	JESD22-B102	Pass
11	Drop Test	JESD22-B111	Pass
12	Adhesion Strength	Push Test>10 lb	Pass

NOTES

A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuits' applicable established test performance criteria and measurement instructions.
C. The parts covered by this specification document are subject to Mini-Circuits' standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/terms/viewterm.html